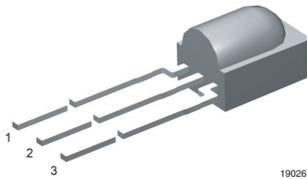


IR Receiver Modules for Remote Control Systems



MECHANICAL DATA

Pinning

1 = OUT, 2 = GND, 3 = V_S

FEATURES

- Low supply current
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against EMI
- Supply voltage: 2.7 V to 5.5 V
- Suitable for short bursts: burst length ≥ 6 carrier cycles
- Improved immunity against ambient light
- Insensitive to supply voltage ripple and noise
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



DESCRIPTION

The TSOP581.. series are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

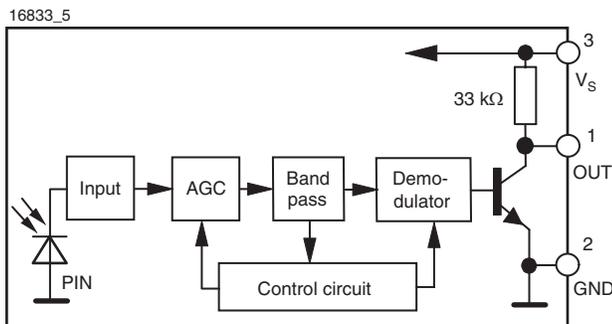
The demodulated output signal can directly be decoded by a microprocessor. The main benefit of the TSOP581.. is the compatibility to all IR remote control data formats.

This component has not been qualified according to automotive specifications.

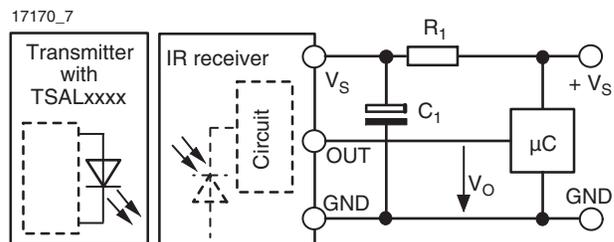
PARTS TABLE

CARRIER FREQUENCY	SHORT BURSTS AND HIGH DATA RATES (AGC1)
30 kHz	TSOP58130
33 kHz	TSOP58133
36 kHz	TSOP58136
38 kHz	TSOP58138
40 kHz	TSOP58140
56 kHz	TSOP58156

BLOCK DIAGRAM



APPLICATION CIRCUIT



The external components R_1 and C_1 are optional to improve the robustness against electrical overstress (typical values are $R_1 = 100 \Omega$, $C_1 = 0.1 \mu\text{F}$).

The output voltage V_O should not be pulled down to a level below 1 V by the external circuit.

The capacitive load at the output should be less than 2 nF.



ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Supply voltage (pin 3)		V_S	- 0.3 to + 6.0	V
Supply current (pin 3)		I_S	5	mA
Output voltage (pin 1)		V_O	- 0.3 to 5.5	V
Voltage at output to supply		$V_S - V_O$	- 0.3 to ($V_S + 0.3$)	V
Output current (pin 1)		I_O	5	mA
Junction temperature		T_J	100	°C
Storage temperature range		T_{stg}	- 25 to + 85	°C
Operating temperature range		T_{amb}	- 25 to + 85	°C
Power consumption	$T_{amb} \leq 85\text{ °C}$	P_{tot}	10	mW
Soldering temperature	$t \leq 10\text{ s}$, 1 mm from case	T_{sd}	260	°C

Note

(1) Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

ELECTRICAL AND OPTICAL CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current (pin 3)	$E_v = 0, V_S = 5\text{ V}$	I_{SD}	0.65	0.85	1.05	mA
	$E_v = 40\text{ klx}$, sunlight	I_{SH}		0.95		mA
Supply voltage		V_S	2.7		5.5	V
Transmission distance	$E_v = 0$, test signal see fig. 1, IR diode TSAL6200, $I_F = 400\text{ mA}$	d		40		m
Output voltage low (pin 1)	$I_{OSL} = 0.5\text{ mA}$, $E_e = 0.7\text{ mW/m}^2$, test signal see fig. 1	V_{OSL}			100	mV
Minimum irradiance	Pulse width tolerance: $t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig. 1	$E_e\text{ min.}$		0.3	0.45	mW/m ²
Maximum irradiance	$t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$, test signal see fig. 1	$E_e\text{ max.}$	30			W/m ²
Directivity	Angle of half transmission distance	$\phi_{1/2}$		± 45		deg

Note

(1) $T_{amb} = 25\text{ °C}$, unless otherwise specified

TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ °C}$, unless otherwise specified

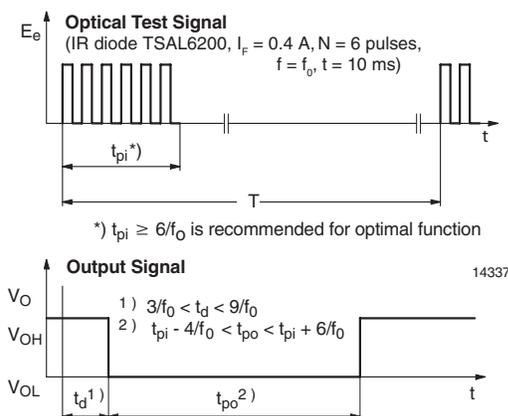


Fig. 1 - Output Active Low

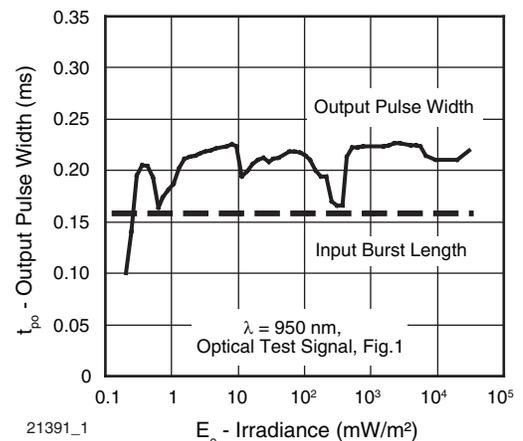


Fig. 2 - Pulse Length and Sensitivity in Dark Ambient

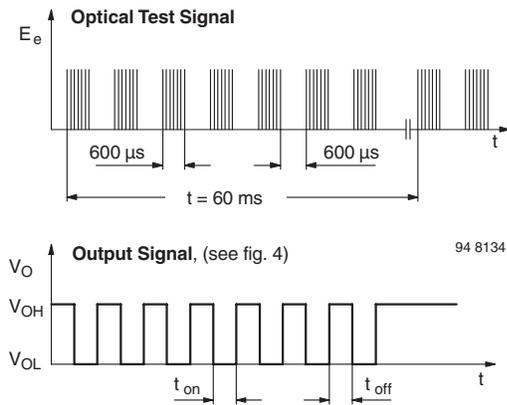


Fig. 3 - Output Function

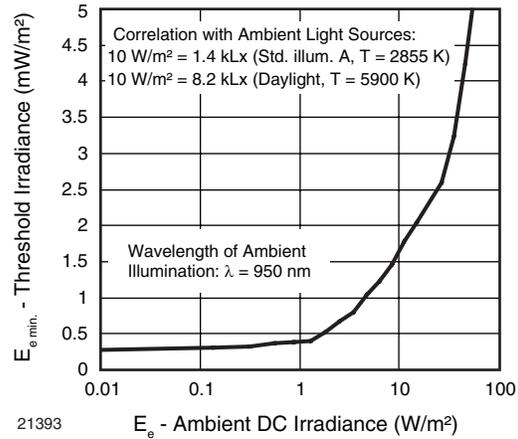


Fig. 6 - Sensitivity in Bright Ambient

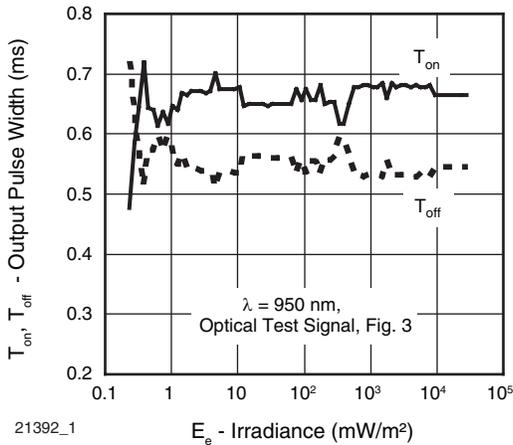


Fig. 4 - Output Pulse Diagram

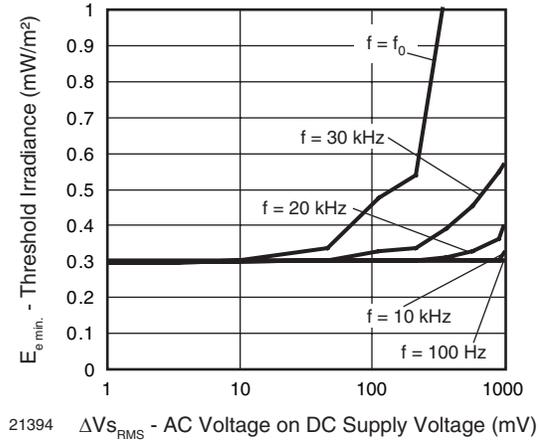


Fig. 7 - Sensitivity vs. Supply Voltage Disturbances

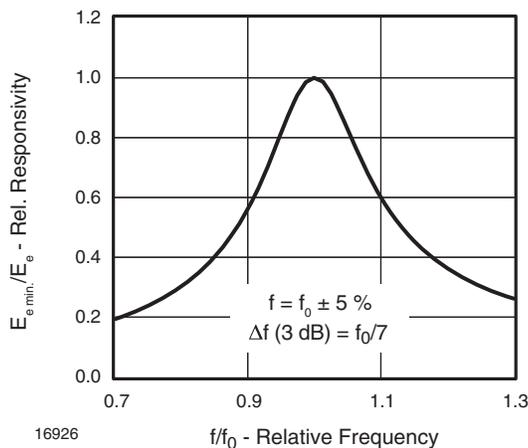


Fig. 5 - Frequency Dependence of Responsivity

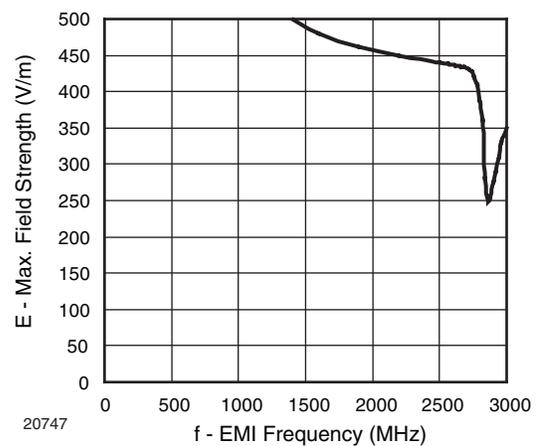


Fig. 8 - Sensitivity vs. Electric Field Disturbances

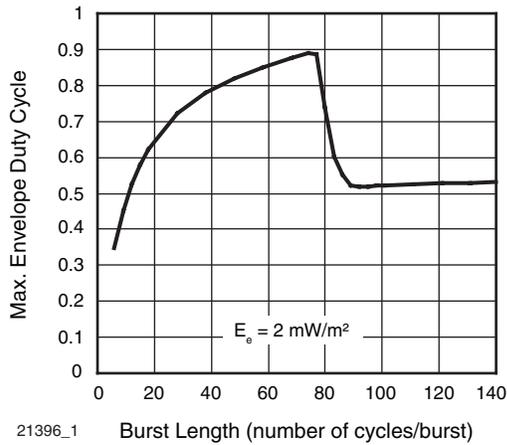


Fig. 9 - Max. Envelope Duty Cycle vs. Burst Length

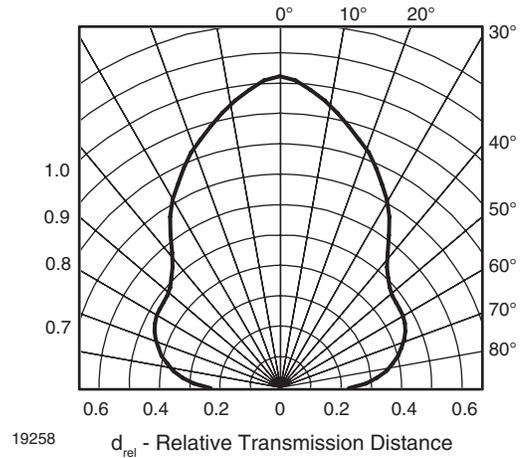


Fig. 12 - Horizontal Directivity

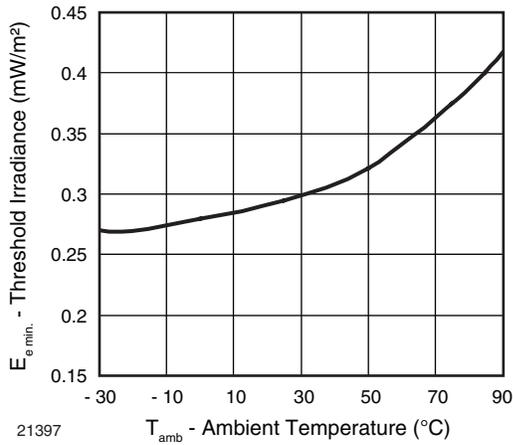


Fig. 10 - Sensitivity vs. Ambient Temperature

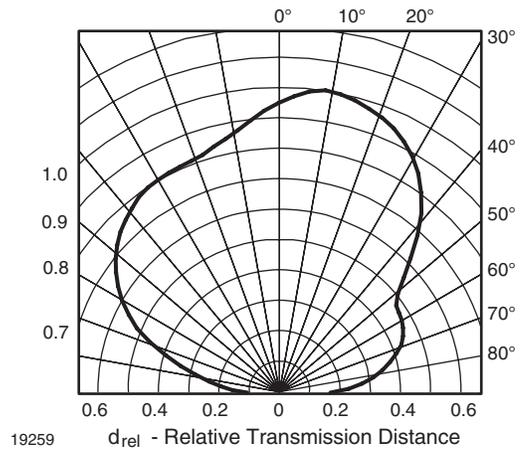


Fig. 13 - Vertical Directivity

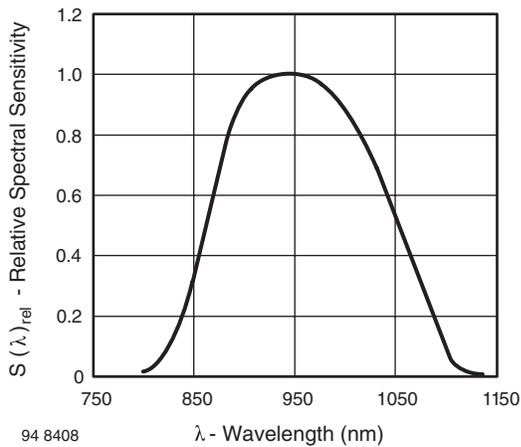


Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

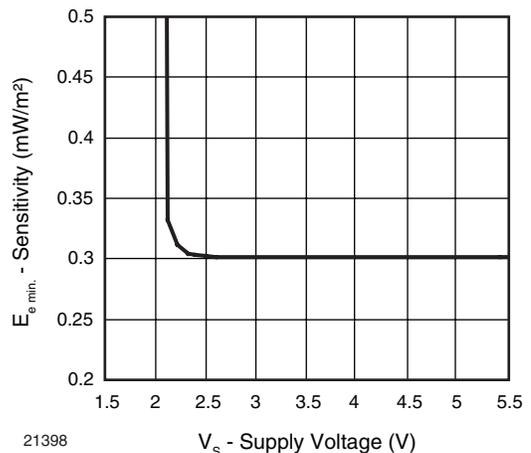


Fig. 14 - Sensitivity vs. Supply Voltage

SUITABLE DATA FORMAT

The TSOP581.. series is designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the TSOP581.. in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signals at any frequency
- Modulated IR signals from common fluorescent lamps (example of noise pattern is shown in figure 15)

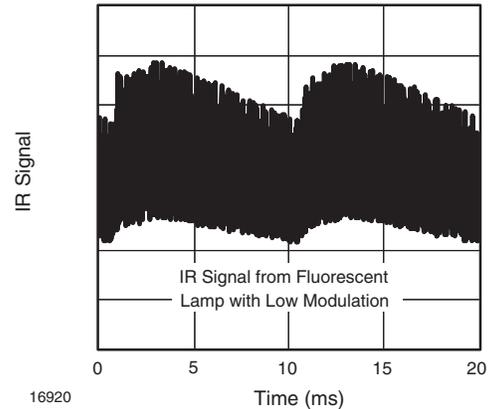


Fig. 15 - IR Signal from Fluorescent Lamp with Low Modulation

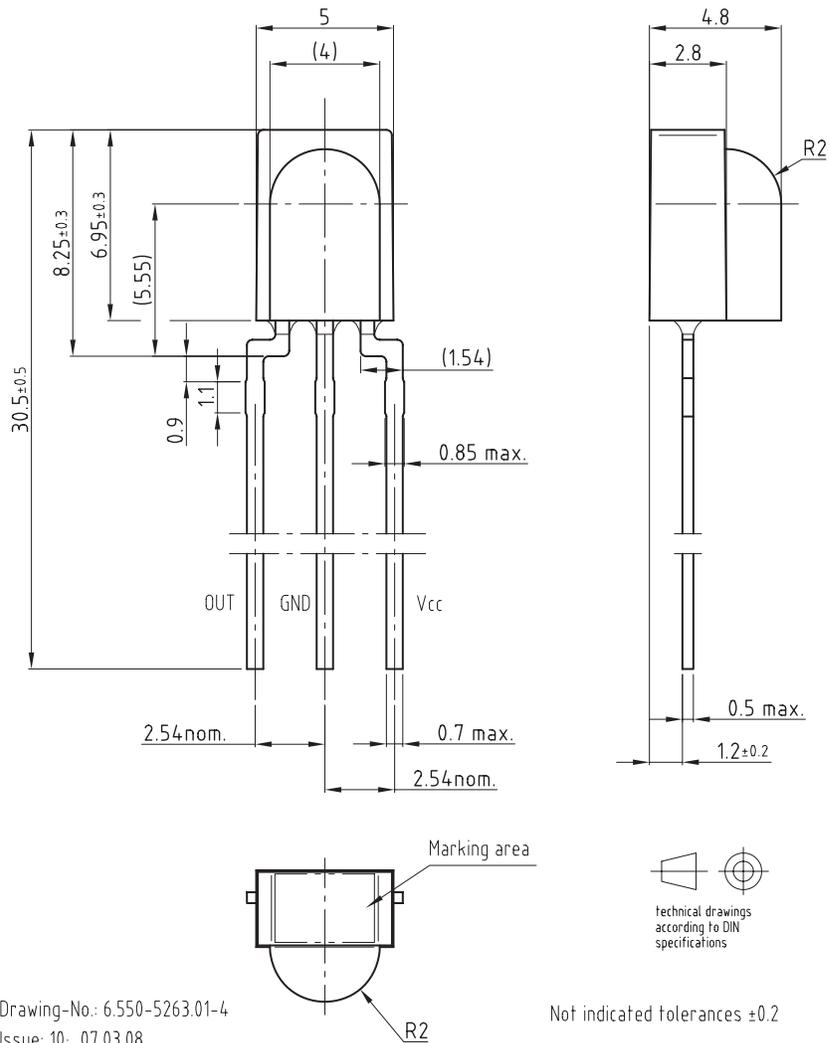
	TSOP581..
Minimum burst length	6 cycles/burst
After each burst of length a minimum gap time is required of	6 to 70 cycles ≥ 10 cycles
For bursts greater than a minimum gap time in the data stream is needed of	70 cycles > 1.1 x burst length
Maximum number of continuous short bursts/second	2000
Compatible to NEC code	yes
Compatible to RC5/RC6 code	yes
Compatible to RCMM code	yes
Compatible to RECS-80 code	yes
Compatible to r-Step and r-Map data format	yes
Compatible to XMP data format	yes
Suppression of interference from fluorescent lamps	Most common disturbance signals are suppressed

Note

For data formats with long bursts (10 carrier cycles or longer) we recommend the TSOP582.. because of the better noise suppression.



PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.550-5263.01-4
Issue: 10; 07.03.08

19009



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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